

Dual 9 MHz Precision Operational Amplifier

Data Sheet OP285

FEATURES

Low offset voltage: 250 µV Low noise: 6 nV/√Hz Low distortion: 0.0006% High slew rate: 22 V/µs Wide bandwidth: 9 MHz Low supply current: 5 mA Low offset current: 2 nA Unity-gain stable 8-lead SOIC_N package

APPLICATIONS

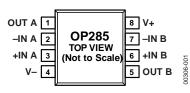
High performance audio Active filters Fast amplifiers Integrators

GENERAL DESCRIPTION

The OP285 is a precision high-speed amplifier featuring the Butler Amplifier front-end. This new front-end design combines the accuracy and low noise performance of bipolar transistors with the speed of JFETs. This yields an amplifier with high slew rates, low offset and good noise performance at low supply currents. Bias currents are also low compared to bipolar designs.

The OP285 offers the slew rate and low power of a JFET amplifier combined with the precision, low noise and low drift of a bipolar amplifier. Input offset voltage is laser-trimmed and guaranteed less than 250 μV . This makes the OP285 useful in dc-coupled or summing applications without the need for special selections or the added noise of additional offset adjustment circuitry. Slew rates of 22 V/ μs and a bandwidth of 9 MHz make the OP285 one of the most accurate medium speed amplifiers available.

PIN CONNECTION



8-Lead Narrow Body SOIC

The combination of low noise, speed and accuracy can be used to build high speed instrumentation systems. Circuits such as instrumentation amplifiers, ramp generators, bi-quad filters and dc-coupled audio systems are all practical with the OP285. For applications that require long term stability, the OP285 has a guaranteed maximum long term drift specification.

The OP285 is specified over the XIND—extended industrial—(-40°C to +85°C) temperature range. The OP285 is available in an 8-lead SOIC_N surface mount package.

$\label{eq:continuous} OP285 — SPECIFICATIONS \ (@\ Vs = \pm 15.0\ V,\ TA = 25^{\circ}C,\ unless\ otherwise\ noted.)$

					Unit
V_{OS}			35	250	μV
Vos	$-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le +85^{\circ}\text{C}$			600	μV
I_{B}	$V_{CM} = 0 V$		100	350	nA
I_{B}	$V_{CM} = 0 \text{ V}, -40^{\circ}\text{C} \le T_{A} \le +85^{\circ}\text{C}$			400	nA
I_{OS}	$V_{CM} = 0 V$		2	±50	nA
I_{OS}	$V_{CM} = 0 \text{ V}, -40^{\circ}\text{C} \le T_{A} \le +85^{\circ}\text{C}$		2	± 100	nA
V_{CM}		-10.5		10.5	V
CMRR	$V_{CM} = \pm 10.5 \text{ V},$				
	$-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le +85^{\circ}\text{C}$	80	106		dB
A_{VO}		250			V/mV
A_{VO}	$R_L = 2 \text{ k}\Omega, -40^{\circ}\text{C} \le T_A \le +85^{\circ}\text{C}$	175			V/mV
A_{VO}	$R_{\rm L}$ = 600 Ω		200		V/mV
:			7.5		pF
			3.7		pF
ΔV_{OS}	Note 1			300	μV
$\Delta V_{OS}/\Delta T$			1		μV/°C
V_{0}	$RL = 2 k\Omega$	-13.5	+13.9	+13.5	V
	$RL = 2 k\Omega, -40^{\circ}C \le T_A \le +85^{\circ}C$		+13.9	+13	V
	$RL = 600 \Omega, V_S = \pm 18 V$		-16/+14		V
PSRR	$V_s = \pm 4.5 \text{ V to } \pm 18 \text{ V}$	85	111		dB
1014		80			dB
Icv					
31			4	5	mA
Isv					
31	$-40^{\circ}\text{C} \le \text{T}_{A} \le +85^{\circ}\text{C}$			5.5	mA
VS	A	±4.5		±22	V
SR	$R_r = 2 \text{ kO}$	15	2.2		V/µs
-	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1				MHz
			_		Degrees
	To 0.1%, 10 V Step				ns
"					ns
L'S			150		110
			-104		dB
e					nV/√Hz
					$\frac{nV}{\sqrt{Hz}}$
1.			-		pA/√Hz
			0.5		
			>12.9		dBu
	$\begin{array}{c} V_{OS} \\ I_{B} \\ I_{OS} \\ I_{OS} \\ V_{CM} \\ CMRR \\ \\ A_{VO} \\ A_{VO} \\ A_{VO} \\ \\ \Delta V_{OS} \\ \Delta V_{OS}/\Delta T \\ \\ V_{O} \\ \\ V_{O} \\ \\ V_{O} \\ \\ \end{array}$	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$

Specifications subject to change without notice.

NOTE 1 Long-term offset voltage is guaranteed by a 1,000 hour life test performed on three independent wafer lots at 125 $^{\circ}$ C, with an LTPD of 1.3.

ABSOLUTE MAXIMUM RATINGS1

112002012111111111111111111111111111111
Supply Voltage
Input Voltage ²
Differential Input Voltage ² ±7.5 V
Output Short-Circuit Duration to Gnd ³ Indefinite
Storage Temperature Range
SOIC_N Package65°C to +150°C
Operating Temperature Range
OP285G
Junction Temperature Range
SOIC_N Package65°C to +150°C
Lead Temperature Range (Soldering 60 Sec) 300°C

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

Package Type	$\theta_{\mathrm{JA}}^{\mathrm{4}}$	$\theta_{ m JC}$	Unit
8-Lead SOIC_N	158	43	°C/W

NOTES

 1 Absolute Maximum Ratings apply to packaged parts, unless otherwise noted. 2 For supply voltages less than ± 7.5 V, the absolute maximum input voltage is equal to the supply voltage.

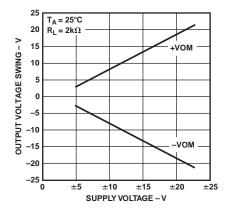
 3Shorts to either supply may destroy the device. See data sheet for full details. $^4\theta_{JA}$ is specified for the worst case conditions, i.e., θ_{JA} is specified for device soldered in circuit board for SOIC package.

ESD CAUTION

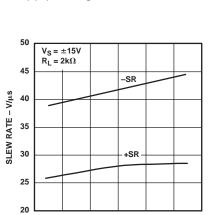


ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

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TPC 1. Output Voltage Swing vs. Supply Voltage



TPC 4. Slew Rate vs. Temperature

25

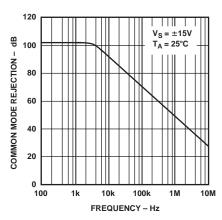
TEMPERATURE - °C

50

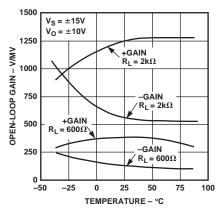
75

100

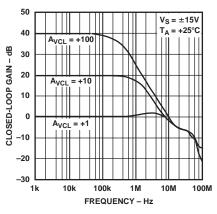
-25



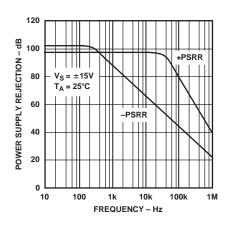
TPC 7. Common-Mode Rejection vs. Frequency



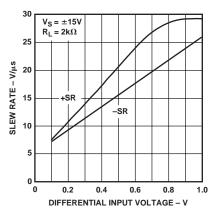
TPC 2. Open-Loop Gain vs. Temperature



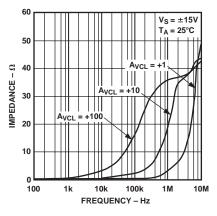
TPC 5. Closed-Loop Gain vs. Frequency



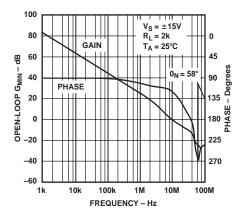
TPC 8. Power Supply Rejection vs. Frequency



TPC 3. Slew Rate vs. Differential Input Voltage



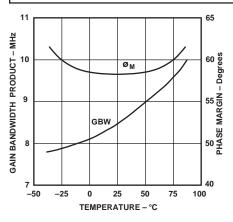
TPC 6. Closed-Loop Output Imped ance vs. Frequency



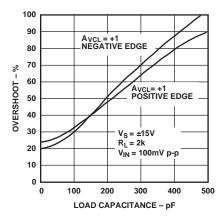
TPC 9. Open-Loop Gain, Phase vs. Frequency

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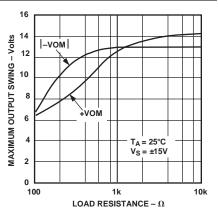
Typical Performance Characteristics—OP285



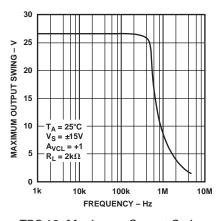
TPC 10. Gain Bandwidth Product, Phase Margin vs. Temperature



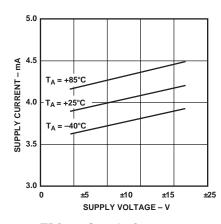
TPC 11. Small-Signal Overshoot vs.| Load Capacitance



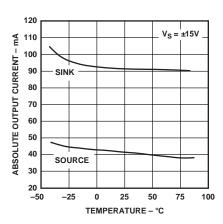
TPC 12. Maximum Output Voltage vs. Load Resistance



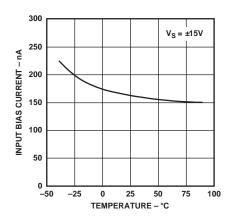
TPC 13. Maximum Output Swing vs. Frequency



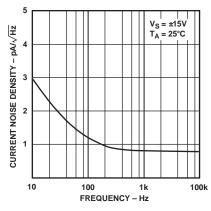
TPC 14. Supply Current vs. Supply Voltage



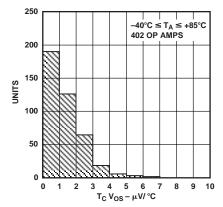
TPC 15. Short Circuit Current vs. Temperature



TPC 16. Input Bias Current vs. Temperature

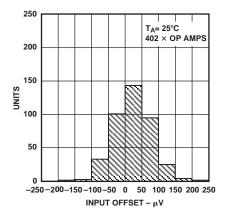


TPC 17. Current Noise Density vs. Frequency

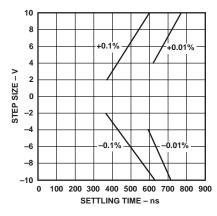


TPC 18. $t_C V_{OS}$ Distribution

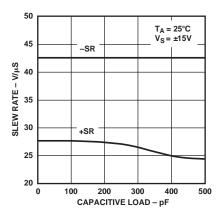
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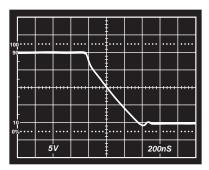
TPC 19. Input Offset (V_{OS}) Distribution



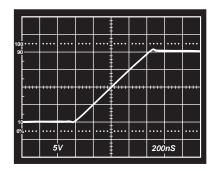
TPC 20. Settling Time vs. Step Size



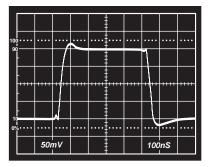
TPC 21. Slew Rate vs. Capacitive Load



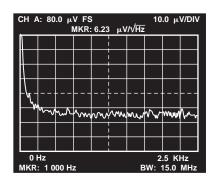
TPC 22. Negative Slew Rate $R_L = 2 k\Omega$, $V_S = \pm 15 V$, $A_V = +1$



TPC 23. Positive Slew Rate $RL = 2 k\Omega$, $V_S = \pm 15 V$, $A_V = +1$



TPC 24. Small Signal Response $R_L = 2 k\Omega$, $V_S = \pm 15 V$, $A_V = +1$



TPC 25. OP285 Voltage Noise Density vs. Frequency $V_S = \pm 15 \ V$, $A_V = 1000$

APPLICATIONS

Short-Circuit Protection

The OP285 has been designed with inherent short-circuit protection to ground. An internal 30 Ω resistor, in series with the output, limits the output current at room temperature to $I_{SC}+=40$ mA and $I_{SC}-=-90$ mA, typically, with ± 15 V supplies.

However, shorts to either supply may destroy the device when excessive voltages or current are applied. If it is possible for a user to short an output to a supply, for safe operation, the output current of the OP285 should be design-limited to ± 30 mA, as shown in Figure 1.

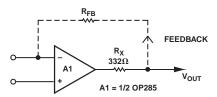


Figure 1. Recommended Output Short-Circuit Protection

Input Over Current Protection

The maximum input differential voltage that can be applied to the OP285 is determined by a pair of internal Zener diodes connected across the inputs. They limit the maximum differential input voltage to ± 7.5 V. This is to prevent emitter-base iunction breakdown from occurring in the input stage of the OP285 when very large differential voltages are applied. However, in order to preserve the OP285's low input noise voltage, internal resistance in series with the inputs were not used to limit the current in the clamp diodes. In small-signal applications, this is not an issue; however, in industrial applications, where large differential voltages can be inadvertently applied to the device, large transient currents can be made to flow through these diodes. The diodes have been designed to carry a current of ± 8 mA; and, in applications where the OP285's differential voltage were to exceed ± 7.5 V, the resistor values shown in Figure 2 safely limit the diode current to ±8 mA.

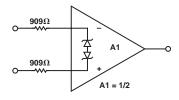


Figure 2. OP285 Input Over Current Protection

Output Voltage Phase Reversal

Since the OP285's input stage combines bipolar transistors for low noise and p-channel JFETs for high speed performance, the output voltage of the OP285 may exhibit phase reversal if either of its inputs exceed its negative common-mode input voltage. This might occur in very severe industrial applications where a sensor or system fault might apply very large voltages on the inputs of the OP285. Even though the input voltage range of the OP285 is ± 10.5 V, an input voltage of approximately -13.5 V will cause output voltage phase reversal. In inverting amplifier configurations, the OP285's internal 7.5 V input clamping diodes will prevent phase reversal; however, they will not prevent this effect from occurring in noninverting applications. For these

applications, the fix is a simple one and is illustrated in Figure 3. A 3.92 k Ω resistor in series with the noninverting input of the OP285 cures the problem.

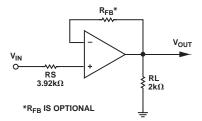


Figure 3. Output Voltage Phase Reversal Fix

Overload or Overdrive Recovery

Overload or overdrive recovery time of an operational amplifier is the time required for the output voltage to recover to a rated output voltage from a saturated condition. This recovery time is important in applications where the amplifier must recover quickly after a large abnormal transient event. The circuit shown in Figure 4 was used to evaluate the OP285's overload recovery time. The OP285 takes approximately 1.2 μ s to recover to V_{OUT} = +10 V_{OUT} and approximately 1.5 μ s to recover to V_{OUT} = -10 V_{OUT} .

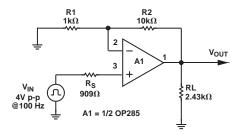


Figure 4. Overload Recovery Time Test Circuit

Driving the Analog Input of an A/D Converter

Settling characteristics of operational amplifiers also include the amplifier's ability to recover, i.e., settle, from a transient output current load condition. When driving the input of an A/D converter, especially successive-approximation converters, the amplifier must maintain a constant output voltage under dynamically changing load current conditions. In these types of converters, the comparison point is usually diode clamped, but it may deviate several hundred millivolts resulting in high frequency modulation of the A/D input current. Amplifiers that exhibit high closed-loop output impedances and/or low unity-gain crossover frequencies recover very slowly from output load current transients. This slow recovery leads to linearity errors or missing codes because of errors in the instantaneous input voltage. Therefore, the amplifier chosen for this type of application should exhibit low output impedance and high unity-gain bandwidth so that its output has had a chance to settle to its nominal value before the converter makes its comparison.

The circuit in Figure 5 illustrates a settling measurement circuit for evaluating the recovery time of an amplifier from an output load current transient. The amplifier is configured as a follower with a very high speed current generator connected to its output. In this test, a 1 mA transient current was used. As shown in Figure 6, the OP285 exhibits an extremely fast recovery time of 139 ns to 0.01%. Because of its high gain-bandwidth product, high open-loop gain, and low output impedance, the OP285 is ideally suited to drive high speed A/D converters.

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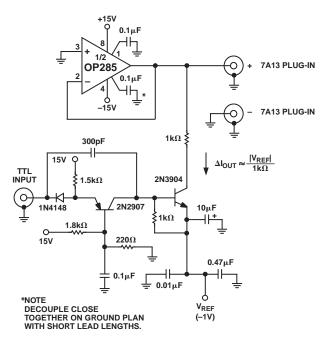


Figure 5. Transient Output Load Current Test Fixture

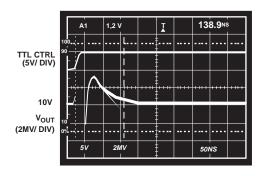


Figure 6. OP285's Output Load Current Recovery Time

16-20V

Measuring Settling Time

The design of OP285 combines high slew rate and wide gain-bandwidth product to produce a fast-settling (ts < $1\,\mu s$) amplifier for 8- and 12-bit applications. The test circuit designed to measure the settling time of the OP285 is shown in Figure 7. This test method has advantages over false-sum node techniques in that the actual output of the amplifier is measured, instead of an error voltage at the sum node. Common-mode settling effects are exercised in this circuit in addition to the slew rate and bandwidth effects measured by the false-sum-node method. Of course, a reasonably flat-top pulse is required as the stimulus.

The output waveform of the OP285 under test is clamped by Schottky diodes and buffered by the JFET source follower. The signal is amplified by a factor of ten by the OP260 and then Schottky-clamped at the output to prevent overloading the oscilloscope's input amplifier. The OP41 is configured as a fast integrator which provides overall dc offset nulling.

High Speed Operation

As with most high speed amplifiers, care should be taken with supply decoupling, lead dress, and component placement. Recommended circuit configurations for inverting and noninverting applications are shown in Figures 8 and Figure 9.

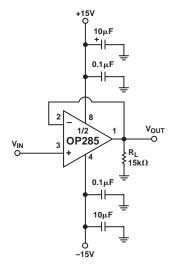


Figure 8. Unity Gain Follower

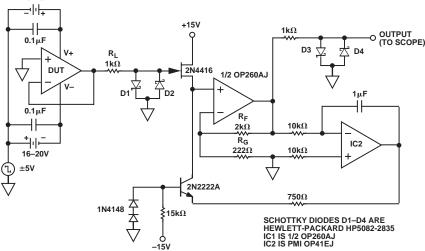


Figure 7. OP285's Settling Time Test Fixture

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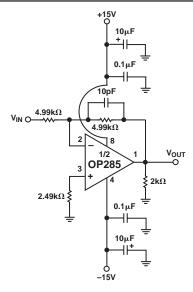


Figure 9. Unity-Gain Inverter

In inverting and noninverting applications, the feedback resistance forms a pole with the source resistance and capacitance (R_S and C_S) and the OP285's input capacitance ($C_{\rm IN}$), as shown in Figure 10. With R_S and R_F in the kilohm range, this pole can create excess phase shift and even oscillation. A small capacitor, C_{FB} , in parallel with R_{FB} eliminates this problem. By setting R_S (C_S + $C_{\rm IN}$) = $R_{FB}C_{FB}$, the effect of the feedback pole is completely removed.

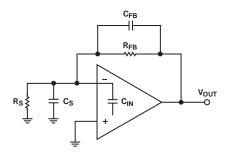


Figure 10. Compensating the Feedback Pole

High-Speed, Low-Noise Differential Line Driver

The circuit of Figure 11 is a unique line driver widely used in industrial applications. With $\pm 18~V$ supplies, the line driver can deliver a differential signal of 30 V p-p into a 2.5 k Ω load. The high slew rate and wide bandwidth of the OP285 combine to yield a full power bandwidth of 130 kHz while the low noise front end produces a referred-to-input noise voltage spectral density of 10 nV/ $\!\!\!\!/\text{Hz}$. The design is a transformerless, balanced transmission system where output common-mode rejection of noise is of paramount importance. Like the transformer-based design, either output can be shorted to ground for unbalanced line driver applications without changing the circuit gain of 1. Other circuit gains can be set according to the equation in the diagram. This allows the design to be easily set to noninverting, inverting, or differential operation.

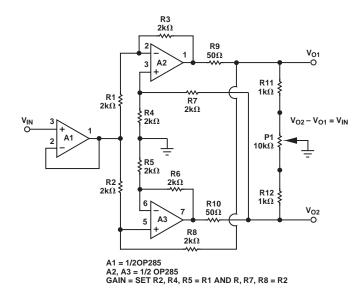


Figure 11. High-Speed, Low-Noise Differential Line Driver

Low Phase Error Amplifier

The simple amplifier configuration of Figure 12 uses the OP285 and resistors to reduce phase error substantially over a wide frequency range when compared to conventional amplifier designs. This technique relies on the matched frequency characteristics of the two amplifiers in the OP285. Each amplifier in the circuit has the same feedback network which produces a circuit gain of 10. Since the two amplifiers are set to the same gain and are matched due to the monolithic construction of the OP285, they will exhibit identical frequency response. Recall from feedback theory that a pole of a feedback network becomes a zero in the loop gain response. By using this technique, the dominant pole of the amplifier in the feedback loop compensates for the dominant pole of the main amplifier,

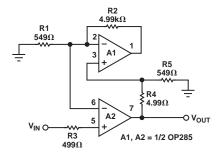


Figure 12. Cancellation of A2's Dominant Pole by A1

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thereby reducing phase error dramatically. This is shown in Figure 13 where the 10x composite amplifier's phase response exhibits less than 1.5° phase shift through 500 kHz. On the other hand, the single gain stage amplifier exhibits 25° of phase shift over the same frequency range. An additional benefit of the low phase error configuration is constant group delay, by virtue of constant phase shift at all frequencies below 500 kHz. Although this technique is valid for minimum circuit gains of 10, actual closed-loop magnitude response must be optimized for the amplifier chosen.

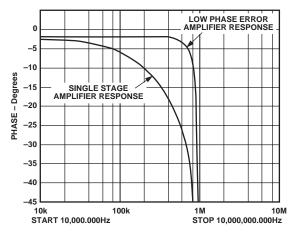


Figure 13. Phase Error Comparison

For a more detailed treatment on the design of low phase error amplifiers, see Application Note AN-107.

Fast Current Pump

A fast, 30 mA current source, illustrated in Figure 14, takes advantage of the OP285's speed and high output current drive. This is a variation of the Howland current source where a second amplifier, A2, is used to increase load current accuracy and output voltage compliance. With supply voltages of $\pm 15~\rm V$, the output voltage compliance of the current pump is $\pm 8~\rm V$. To keep the output resistance in the $M\Omega$ range requires that 0.1% or better resistors be used in the circuit. The gain of the current pump can be easily changed according to the equations shown in the diagram.

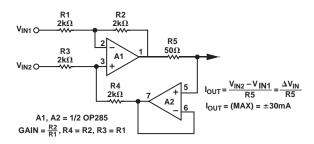


Figure 14. A Fast Current Pump

A Low Noise, High Speed Instrumentation Amplifier

A high speed, low noise instrumentation amplifier, constructed with a single OP285, is illustrated in Figure 15. The circuit exhibits less than 1.2 μV p-p noise (RTI) in the 0.1 Hz to 10 Hz band and an input noise voltage spectral density of 9 nV/Hz (1 kHz) at a gain of 1000. The gain of the amplifier is easily set by R_G according to the formula:

$$\frac{V_{OUT}}{V_{IN}} = \frac{9.98 \; k\Omega}{R_G} + 2$$

The advantages of a two op amp instrumentation amplifier based on a dual op amp is that the errors in the individual amplifiers tend to cancel one another. For example, the circuit's input offset voltage is determined by the input offset voltage matching of the OP285, which is typically less than 250 $\mu V.$

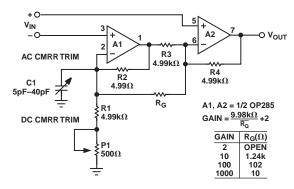


Figure 15. A High-Speed Instrumentation Amplifier

Common-mode rejection of the circuit is limited by the matching of resistors R1 to R4. For good common-mode rejection, these resistors ought to be matched to better than 1%. The circuit was constructed with 1% resistors and included potentiometer P1 for trimming the CMRR and a capacitor C1 for trimming the CMRR. With these two trims, the circuit's common-mode rejection was better than 95 dB at 60 Hz and better than 65 dB at 10 kHz. For the best common-mode rejection performance, use a matched (better than 0.1%) thin-film resistor network for R1 through R4 and use the variable capacitor to optimize the circuit's CMR.

The instrumentation amplifier exhibits very wide small- and large-signal bandwidths regardless of the gain setting, as shown in the table. Because of its low noise, wide gain-bandwidth product, and high slew rate, the OP285 is ideally suited for high speed signal conditioning applications.

Circuit	R_G	Circuit Bandwidth		
Gain	(Ω)	$V_{OUT} = 100 \text{ mV p-p}$	$V_{OUT} = 20 \text{ V p-p}$	
2	Open	5 MHz	780 kHz	
10	Open 1.24 k	1 MHz	460 kHz	
100	102	90 kHz	85 kHz	
1000	10	10 kHz	10 kHz	

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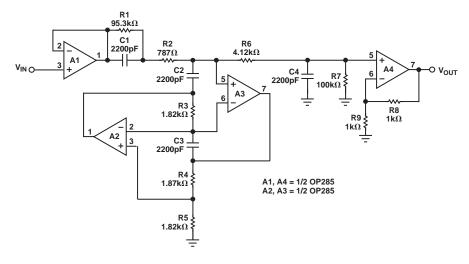


Figure 16. A 3-Pole, 40 kHz Low-Pass Filter

A 3-Pole, 40 kHz Low-Pass Filter

The closely matched and uniform ac characteristics of the OP285 make it ideal for use in GIC (Generalized Impedance Converter) and FDNR (Frequency Dependent Negative Resistor) filter applications. The circuit in Figure 16 illustrates a linear-phase, 3-pole, 40 kHz low-pass filter using an OP285 as an inductance simulator (gyrator). The circuit uses one OP285 (A2 and A3) for the FDNR and one OP285 (Al and A4) as an input buffer and bias current source for A3. Amplifier A4 is configured in a gain of 2 to set the pass band magnitude response to 0 dB. The benefits of this filter topology over classical approaches are that the op amp used in the FDNR is not in the signal path and that the filter's performance is relatively insensitive to component variations. Also, the configuration is such that large signal levels can be handled without overloading any of the filter's internal nodes. As shown in Figure 17, the OP285's symmetric slew rate and low distortion produce a clean, well-behaved transient response.

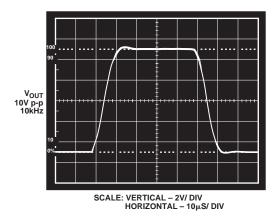


Figure 17. Low-Pass Filter Transient Response

Driving Capacitive Loads

The OP285 was designed to drive both resistive loads to 600 Ω and capacitive loads of over 1000 pF and maintain stability. While there is a degradation in bandwidth when driving capacitive loads, the designer need not worry about device stability. The graph in Figure 18 shows the 0 dB bandwidth of the OP285 with capacitive loads from 10 pF to 1000 pF.

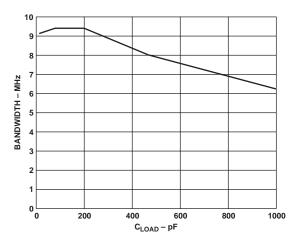


Figure 18. Bandwidth vs. C_{LOAD}

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OP285 SPICE	E Model			
* Node assign			* POLE/ZER	O PAIR AT 1.5MHz/2.7MHz
*		verting input	* R8 21 98	1E3
*	111	verting input positive supply	R9 21 22	1.25E3
*		negative supply	C4 22 98	47.2E-12
*		output	G2 98 21	18 28 1E-3
*			* * POLE AT	100 MU7
* .SUBCKT OI	2285 1 2	99 50 34	*	100 WHIZ
*	1 2	99 30 34	R10 23 98	1
	AGE & POLE A	T 100 MHZ	C5 23 98	1.59E-9
* D2	5.51	2.100	G3 98 23 *	21 28 1
R3 R4	5 51 6 51	2.188 2.188	* POLE AT	100 MHZ
CIN 1 2	1.5E-12	2.100	*	
C2	5 6	364E-12	R11 24 98	1 500.0
II	97 4	100E-3	C6 24 98 G4 98 24	1.59E-9 23 28 1
IOS 1 2 EOS 9 3	1E-9 POLY(1) 26 2	9 25E 6 1	W4 90 24 *	23 28 1
Q1	5 2 7 QX	8 33E-0 1	* COMMON	N-MODE GAIN NETWORK WITH ZERO AT
Q2	6 9 8 QX		1 kHZ *	
R5	7 4	1.672	R12 25 26	1E6
R6	8 4	1.672	C7 25 26 R13 26 98	1.59E-12 1
D1 D2	2 36 1 36	DZ DZ	E2 25 98	POLY(2) 1 98 2 98 0 2.506 2.506
EN	3 1	100 1	*	• •
GN1 0 2	13 0 1		* POLE AT	100 MHZ
GN20 1 *	16 0 1		R14 27 98	1
EREF 98 0	28 0 1		C8 27 98	1.59E-9
EP	97 0	99 0 1	G5 98 27	24 28 1
EM	510	50 0 1	* * OUTDUT	STACE
* * VOLTAGE	NOISE SOUR	∩E	* OUTPUT	STAGE
*	NOISE SOOK	SE	R15 28 99	100E3
DN1 35 10	DEN		R16 28 50	100E3
DN2 10 11	DEN		C9 28 50 ISY 99 50	1 E-6 1.85E-3
VN1 35 0 VN2 0 11	DC 2 DC 2		R17 29 99	100
*	DC 2		R18 29 50	100
	NOISE SOUR	CE	L2 29 34	1E-9
*	DDI		G6 32 50 G7 33 50	27 29 10E-3 29 27 10E-3
DN3 12 13 DN4 13 14	DIN DIN		G8 29 99	99 27 10E-3
VN3 12 0	DC 2		G9 50 29	27 50 10E-3
VN4 0 14	DC 2		V4 30 29	1.3
CN1 13 0	7.53E-3		V5 29 31 F1 29 0	3.8 V4 1
* * CLIDDENIT	NOISE SOUR	CE	F2 0 29	V4 1 V5 1
* CURRENT	NOISE SOUR	CE	D5 27 30	DX
DN5 15 16	DIN		D6 31 27	DX
DN6 16 17	DIN		D7 99 32	DX
VN5 15 0	DC 2		D8 99 33 D9 50 32	DX DY
VN6 0 17 CN2 16 0	DC2 7.53E-3		D10 50 33	DY
*	1.55L-5		*	
		ANT POLE AT 32 HZ *	* MODELS	USED
R7 18 98	1.09E6			$\angle NP(BF = 5E5)$
C3 18 98 G1 98 18	4.55E-9 5 6 4.57E-1		.MODEL DY	
V2 97 19	1.4		.MODEL DY	D(IS = 1E-15 BV = 50)
V3 20 51	1.4		.MODEL DZ	
D3 18 19	DX			EN D(IS = IE-12 RS = 4.35K KF = 1.95E-15 DEL DIN D(IS = IE-12 RS = 77.3E-6
D4 20 18 *	DX			15 AF = 1) .ENDS OP-285
				•

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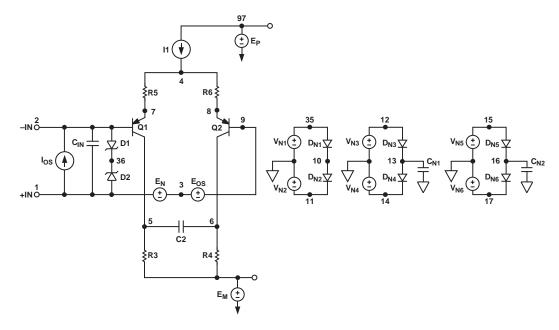


Figure 19a. Spice Diagram

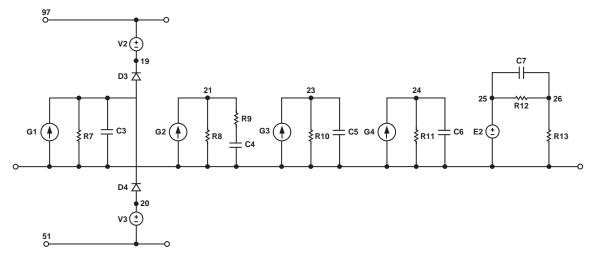


Figure 19b. Spice Diagram

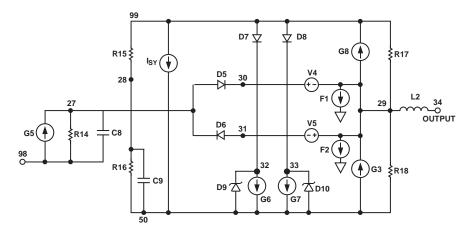
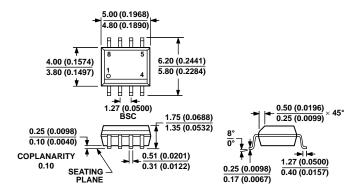


Figure 19c. Spice Diagram

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OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MS-012-AA
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

SIGN.

8-Lead Standard Small Outline Package [SOIC_N] Narrow Body (R-8)

Dimensions shown in millimeters and (inches)

ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Package Option
OP285GS	−40°C to +85°C	8-lead SOIC_N	R-8
OP285GS-REEL	−40°C to +85°C	8-lead SOIC_N	R-8
OP285GS-REEL7	-40°C to +85°C	8-lead SOIC_N	R-8
OP285GSZ	−40°C to +85°C	8-lead SOIC_N	R-8
OP285GSZ-REEL	−40°C to +85°C	8-lead SOIC_N	R-8
OP285GSZ-REEL7	−40°C to +85°C	8-lead SOIC_N	R-8

¹ Z = RoHS Compliant Part.

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REVISION HISTORY

10/2017—Rev. A to Rev. B	
Changes to General Description Section and Pin Connection	on1
Changes to Supply Current Parameter, Specifications Section	on2
Changes to Absolute Maximum Ratings Section	3
Updated Outline Dimensions	14
Moved Ordering Guide	14
Changes to Ordering Guide	14
1/2002—Rev. 0 to Rev. A	
Edits to Ordering Guide	3
Deleted Wafer Test Limits	3
Deleted Dice Characteristics	3

7/1992—Revision 0: Initial Version



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